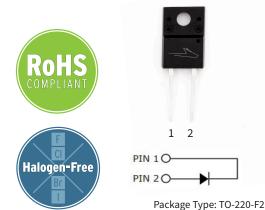


3rd Generation 600 V, 3 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.



Marking: C3D03060

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Features

- Optimized for PFC Boost Diode Application
- Zero Reverse Recovery Current / Forward **Recovery Voltage**
- Temperature-Independent Switching Behavior
- **Fully Isolated Case**
- **Extremely Fast Switching**

Typical Applications

- Switch Mode Power Supplies (SMPS)
- Free Wheeling Diodes in Inverter Stages
- Boost for PFC & DC-DC Stages
- Solar Inverters
- AC/DC Converters

Maximum Ratings (T_c = 25°C Unless Otherwise Specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	V _{RRM}	600				
DC Blocking Voltage	V _{DC}	600	V			
		8		T _c = 25 °C	F: 0	
Continuous Forward Current	I _F	3		T _c = 125 °C	Fig. 3	
		2		T _c = 150 °C		
Repetitive Peak Forward Surge Current	I _{FRM}	11	A	$T_c = 25 ^{\circ}\text{C}$, $t_p = 10 \text{ms}$, Half Sine Wave		
		6		$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Wave}$		
Non-Repetitive Forward Surge Current	I _{FSM}	18		$T_c = 25 ^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Wave}$	Fig. 8	
		14.5		$T_c = 110 ^{\circ}\text{C,t}_p = 10 \text{ms, Half Sine Wave}$		
Non-Repetitive Peak Forward		100		$T_c = 25 ^{\circ}\text{C}, t_p = 10 \mu\text{s}, \text{Pulse}$	F: 0	
Surge Current	F,Max	80		$T_{c} = 110^{\circ}\text{C}, t_{p} = 10 \mu\text{s}, \text{Pulse}$	Fig 8.	
Power Dissipation	P _{tot}	27.3	W	T _c = 25 °C	Fig. 4	
		11.8		T _c =110 °C		
Diode dV/dt Ruggedness	dV/dt	200	V/ns	V _R = 0-600V		
i²t value (Per Leg)	∫i²dt	1.6	A ² s	$T_c = 25 ^{\circ}\text{C}, t_p = 10 \text{ms}$		
		1.0		$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}$		

Electrical Characteristics

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes
	V	1.5	1.7	,,	I _F = 3 A, T _j = 25 °C	F: 1
Forward Voltage	V _F	1.8	2.4	V	I _F = 3 A, T _j = 175 °C	Fig. 1
Reverse Current		4	20	μА	$V_R = 600 \text{ V}, T_j = 25 \text{ °C}$	Fig. 2
	l _R	8	80		$V_R = 600 \text{ V}, T_j = 175 \text{ °C}$	
Total Capacitive Charge	Q _c	7.6		nC	$V_R = 400 \text{ V}, T_j = 25 \text{ °C}, I_F = 3 \text{ A}$	Fig. 5
Total Capacitance		166		pF	$V_R = 0 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	Fig. 6
	c [14			$V_R = 200 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	
		11			$V_R = 400 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	
Capacitance Stored Energy	E _c	1.1		μJ	V _R = 400 V	Fig. 7

Notes:

SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	R _{0, JC (TYP)}	5.5	°C/W	
Junction Temperature	T _j	-55 to +175	۰٫	
Case & Storage Temperature	T _c	-55 to +175		
TO 220 Mounting Toyana		1	Nm	M3 Screw
TO-220 Mounting Torque	-	8.8	lbf-in	6-32 Screw

Electrostatic Discharge (ESD) Classifications

Parameter	Symbol	Notes
Human Body Model	НВМ	Class 3B (≥ 8000 V)
Charge Device Model	CDM	Class C3 (≥ 1000 V)

Typical Performance

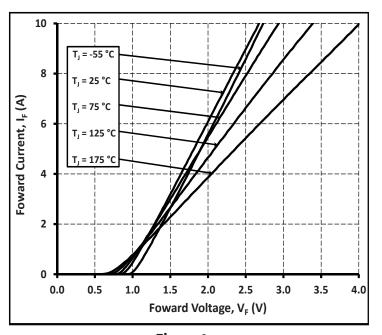


Figure 1Forward Characteristics

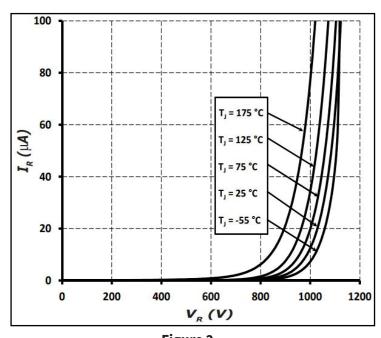


Figure 2Reverse Characteristics

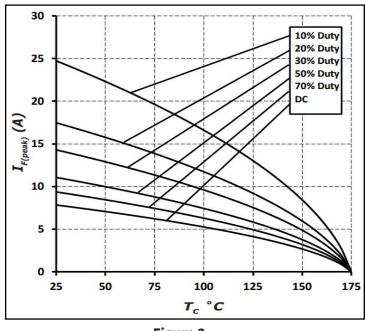


Figure 3Current Derating

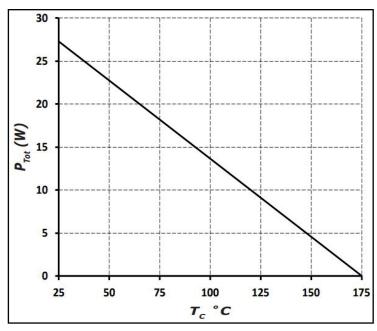
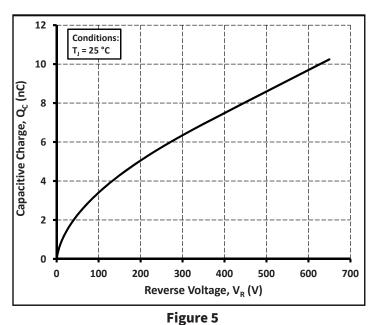


Figure 4Power Derating



Total Capacitance vs. Reverse Voltage

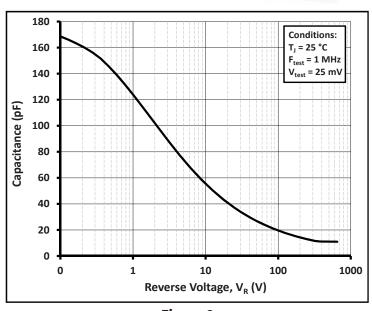
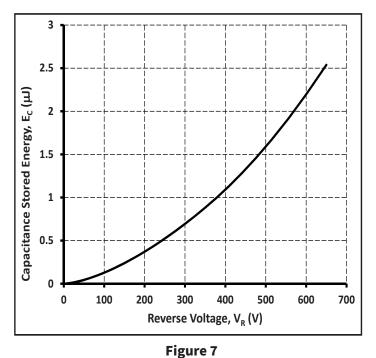
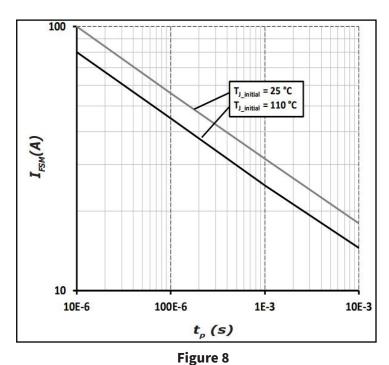


Figure 6Capacitace vs. Reverse Voltage



Capacitance Stored Energy



Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)

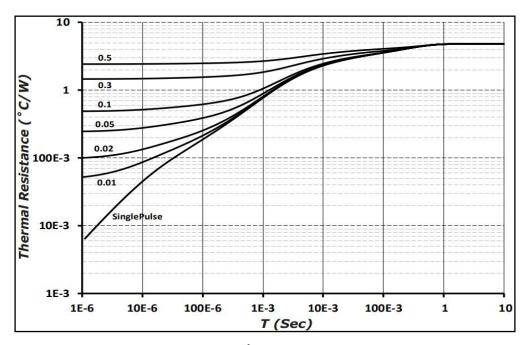
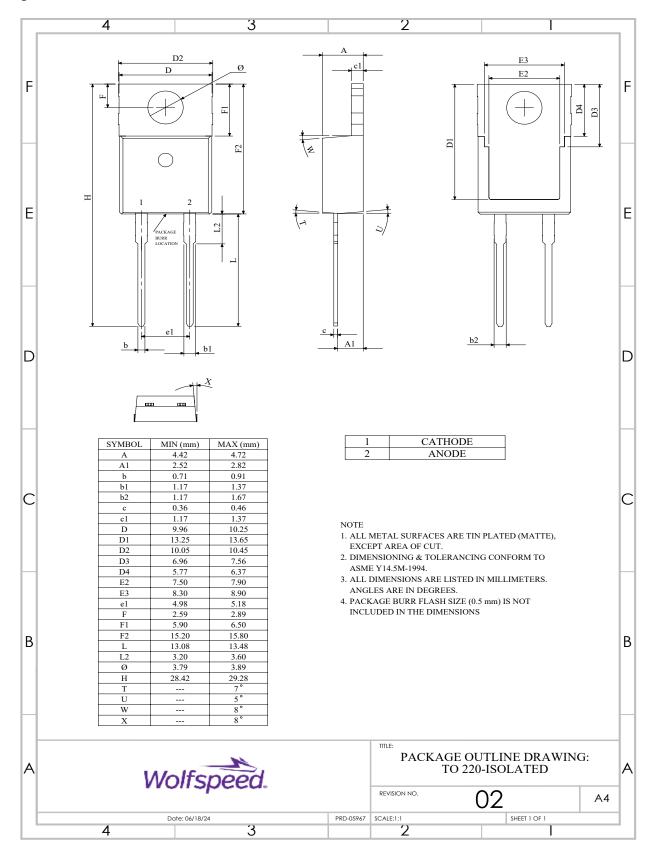


Figure 9Transient Thermal Impedance

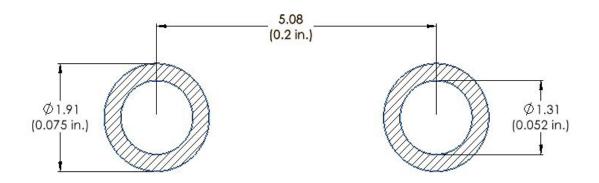
Package Dimensions & Pin-Out

Package: TO-220-F2



Recommended Solder Pad Layout

Primary dimensions shown in mm.



Product Ordering Information

Order Number	Packing Type
C3D03060F	Tube

Revision History

Document Version	Date of Release	Description of Changes
F	February- 2019	Initial Release
7	October-2023	Update Package Drawing Update Landing Pad Updated Branding Updated Package Image
8	November-2023	Correct POD A1, b1, and Q
0	October - 2024	Legal Disclaimer, POD



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